

P/N: L-56BYD

YELLOW

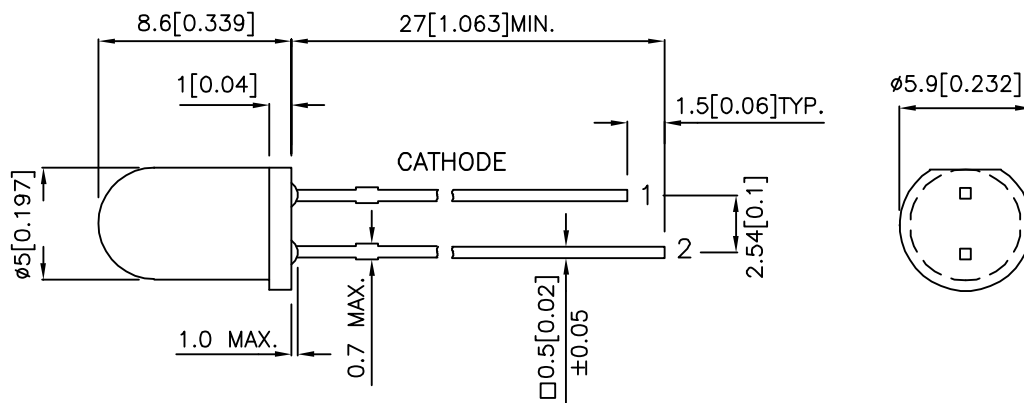
### Features

- T-1 3/4 PACKAGE .
- WITH BUILT-IN BLINKING IC.
- OPERATION VOLTAGE FROM 3.5V TO 14V.
- BLINKING FREQUENCY FROM 3.0Hz TO 1.5Hz.
- RoHS COMPLIANT.

### Description

The Yellow source color devices are made with Gallium Arsenide Phosphide on Gallium Phosphide Yellow Light Emitting Diode.

### Package Dimensions



#### Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is  $\pm 0.25 (0.01)$  unless otherwise noted.
3. Lead spacing is measured where the leads emerge from the package.
4. Specifications are subject to change without notice.

## Selection Guide

Part No.	Dice	Lens Type	Iv (mcd) V=9V		Viewing Angle
			Min.	Typ.	2θ1/2
L-56BYD	YELLOW (GaAsP/GaP)	YELLOW DIFFUSED	5	20	60°

Note:

1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.

## Electrical / Optical Characteristics at TA=25°C

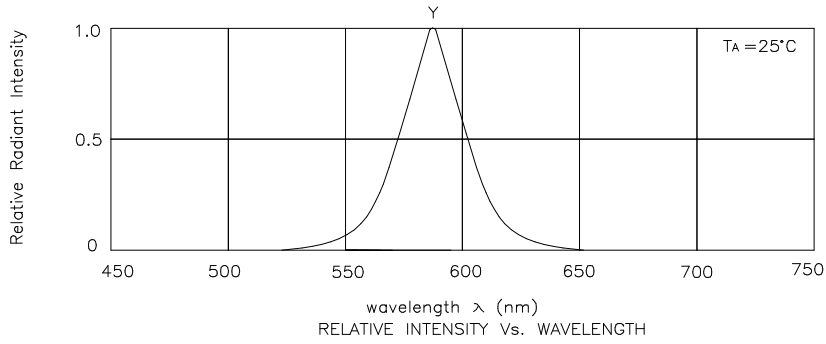
Symbol	Parameter	Device	Min.	Typ.	Max.	Units	Test Conditions
λ <sub>peak</sub>	Peak Wavelength	Yellow		590		nm	
λ <sub>D</sub>	Dominant Wavelength	Yellow		588		nm	
Δλ <sub>1/2</sub>	Spectral Line Half-width	Yellow		35		nm	
I <sub>F</sub>	Forward Current	Yellow	8	22		mA	Min:V <sub>F</sub> =3.5V Typ:V <sub>F</sub> =5V
I <sub>SON</sub>	Supply Current	Yellow		8		mA	V <sub>F</sub> = 3.5V
I <sub>SON</sub>	Supply Current	Yellow		44		mA	V <sub>F</sub> = 14V
f	Blink Frequency	Yellow	1.5		3	Hz	V <sub>F</sub> = 3.5V~14V

## Absolute Maximum Ratings at TA=25°C

Parameter	Yellow	Units
Power dissipation	310	mW
Forward Voltage	14	V
Reverse Voltage	0.5	V
Operating Temperature	-40°C To +70°C	
Storage Temperature	-40°C To +85°C	
Lead Solder Temperature [1]	260°C For 3 Seconds	
Lead Solder Temperature [2]	260°C For 5 Seconds	

Notes:

1. 2mm below package base.
2. 5mm below package base.



Yellow

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